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S/N: 10/718,789

5/14/2007

Docket No.: SUG-176-USAP

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Serial No.: 10/718,789

Confirmation No.: 1591

Applicant: Kazunori HAGIMOTO et al.

Art Unit: 2814

Filed: November 24, 2003

Examiner: Howard Weiss

Docket No: SUG-176-USAP

Customer No: 28892

For: Light-Emitting Device, Method of Fabricating the Same, and

OHMIC Electrode Structure for Semiconductor Device

INFORMATION DISCLOSURE STATEMENT PURSUANT TO 37 C.F.R. §§ 1.56, 1.97, and 1.98

US Patent & Trademark Office Customer Service Window Randolph Building 401 Dulany Street Alexandria, VA 22314

Sir:

In compliance with the dictates of 37 C.F.R. §§ 1.56, 1.97, and 1.98, Applicant hereby submits an Information Disclosure Statement.

Applicant hereby reports the issuance of an Office Action in the corresponding Japanese application. A copy of the references together with PTO Form 1449 listing each of the references is attached hereto. In accordance with MPEP § 609 III A(2), copies of US patent documents are not attached for applications filed after June 30, 2003 (MPEP Rev. 2, May 2004, page 600-128).

It is respectfully requested that the Examiner consider each of these references and indicate such consideration by enclosing an appropriately initialled copy of the enclosed form PTO-1449 with the next communication from the Patent Office.

INFORMATION DISCLOSURE STATEMENT TRANSMITTAL - PAGE 2 OF 2

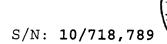
Respectfully submitted,

Ronald R. Snider Attorney of Record Reg. No. 24,962

Date: May 14, 2007

Snider & Associates Ronald R. Snider P.O. Box 27613 Washington, D.C. 20038-7613 (202) 347-2600

RRS/jt





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INFORMATION DISCLOSURE STATEMENT - PTO FORM 1449

U.S. PATENT DOCUMENTS					
Examiner Initials*	U.S. Patent Document Number	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY		
	5,917,202 (JP 9-186365)	Haitz et al.	06-29-1999		

FOREIGN PATENT DOCUMENTS							
Examiner Initials*	Foreign Patent Document Number	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	T**			
	JP 2001-7389 (w/ Eng. Abstract)	Tokyo Shibaura Electric Co.	01-12-2001				
	JP 9-186365 (w/ Eng. Abstract) (5,917,202)	Hewlett Packard Co.	07-15-1997				
	JP 5-251739 (w/ Eng. Abstract)	Tokyo Shibaura Electric Co.	09-28-1993				

Examiner Signature	Date Considered	
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^{*}Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

^{**}Applicant is to place a check mark here if English language translation is attached